NCP1207A

PWM Current-Mode Controller for Free Running Quasi-Resonant Operation

The NCP1207A combines a true current mode modulator and a demagnetization detector to ensure full borderline/critical Conduction Mode in any load/line conditions and minimum drain voltage switching (Quasi−Resonant operation). Due to its inherent skip cycle capability, the controller enters burst mode as soon as the power demand falls below a predetermined level. As this happens at low peak current, no audible noise can be heard. An internal 8.0 μs timer prevents the free−run frequency to exceed 100 kHz (therefore below the 150 kHz CISPR−22 EMI starting limit), while the skip adjustment capability lets the user select the frequency at which the burst foldback takes place.

The Dynamic Self−Supply (DSS) drastically simplifies the transformer design in avoiding the use of an auxiliary winding to supply the NCP1207A. This feature is particularly useful in applications where the output voltage varies during operation (e.g. battery chargers). Due to its high−voltage technology, the IC is directly connected to the high−voltage DC rail. As a result, the short−circuit trip point is not dependent upon any V_{CC} auxiliary level.

The transformer core reset detection is done through an auxiliary winding which, brought via a dedicated pin, also enables fast Overvoltage Protection (OVP). Once an OVP has been detected, the IC permanently latches off.

Finally, the continuous feedback signal monitoring implemented with an overcurrent fault protection circuitry (OCP) makes the final design rugged and reliable.

Features

- Free−Running Borderline/Critical Mode Quasi−Resonant Operation
- Current−Mode with Adjustable Skip−Cycle Capability
- No Auxiliary Winding V_{CC} Operation
- Auto−Recovery Overcurrent Protection
- Latching Overvoltage Protection
- External Latch Triggering, e.g. Via Overtemperature Signal
- 500 mA Peak Current Source/Sink Capability
- Undervoltage Lockout for VCC Below 10 V
- Internal 1.0 ms Soft−Start
- Internal 8.0 μs Minimum T_{OFF}
- Adjustable Skip Level
- Internal Temperature Shutdown
- Direct Optocoupler Connection
- SPICE Models Available for TRANsient Analysis
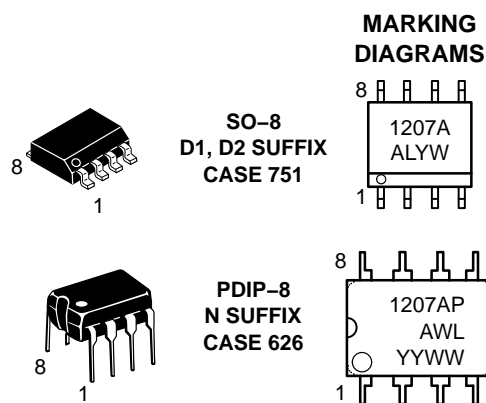- Pb−Free Package is Available

Typical Applications

- AC/DC Adapters for Notebooks, etc.
- Offline Battery Chargers
- Consumer Electronics (DVD Players, Set−Top Boxes, TVs, etc.)
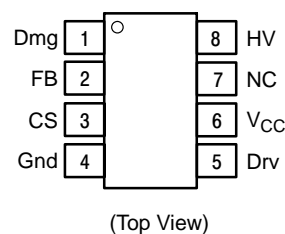- Auxiliary Power Supplies (USB, Appliances, TVs, etc.)

ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS

SO−8
D1, D2 SUFFIX
CASE 751

8 ▯▯▯▯
1207A
ALYW
1 ▯▯▯▯

PDIP−8
N SUFFIX
CASE 626

8
1207AP
AWL
YYWW
1

1207A/P	= Device Code
A	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week

PIN CONNECTIONS

Dmg	1	8	HV
FB	2	7	NC
CS	3	6	V_{CC}
Gnd	4	5	Drv

(Top View)

ORDERING INFORMATION

Device	Package	Shipping[†]
NCP1207ADR2	SOIC−8	2500/Tape & Reel
NCP1207ADR2G	SOIC−8 (Pb−Free)	2500/Tape & Reel
NCP1207AP	PDIP−8	50 Units/Tube

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
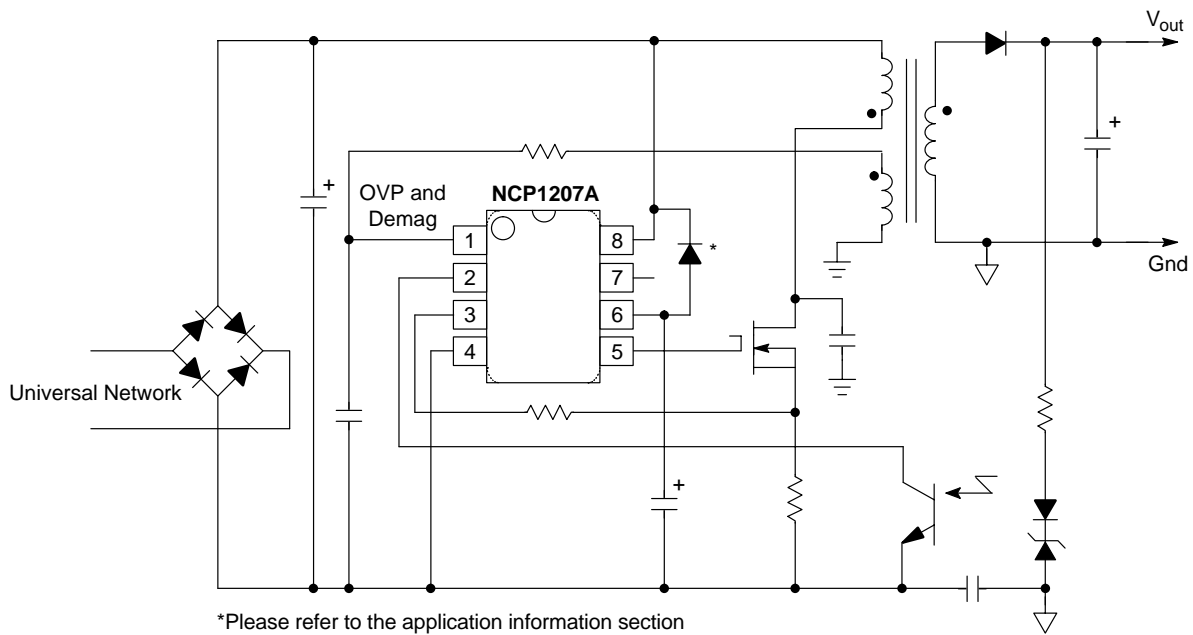
NCP1207A

Figure 1. Typical Application

*Please refer to the application information section

PIN FUNCTION DESCRIPTION

| Pin No.	Pin Name	Function	Description
1	Demag	Core reset detection and OVP	The auxiliary FLYBACK signal ensures discontinuous operation and offers a fixed overvoltage detection level of 7.2 V.
2	FB	Sets the peak current setpoint	By connecting an Optocoupler to this pin, the peak current setpoint is adjusted accordingly to the output power demand. By bringing this pin below the internal skip level, device shuts off.
3	CS	Current sense input and skip cycle level selection	This pin senses the primary current and routes it to the internal comparator via an L.E.B. By inserting a resistor in series with the pin, you control the level at which the skip operation takes place.
4	Gnd	The IC ground	–
5	Drv	Driving pulses	The driver's output to an external MOSFET.
6	V_{CC}	Supplies the IC	This pin is connected to an external bulk capacitor of typically 10 μF.
7	NC	–	This unconnected pin ensures adequate creepage distance.
8	HV	High–voltage pin	Connected to the high–voltage rail, this pin injects a constant current into the V_{CC} bulk capacitor.

NCP1207A
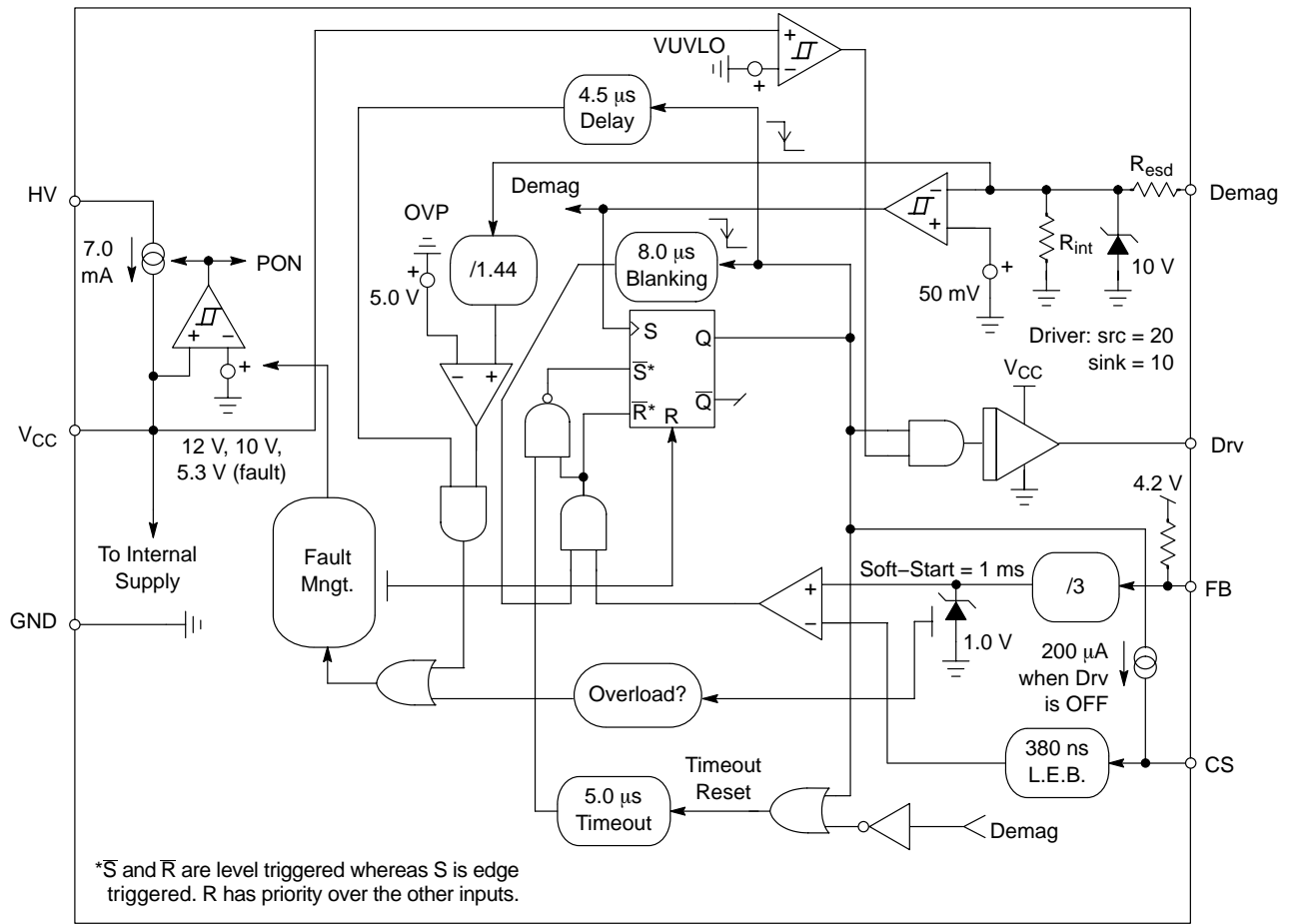
Figure 2. Internal Circuit Architecture

MAXIMUM RATINGS

Rating	Symbol	Value	Units
Power Supply Voltage	V_{CC}, Drv	16	V
Maximum Voltage on all other pins except Pin 8 (HV), Pin 6 (V_{CC}) Pin 5 (Drv) and Pin 1 (Demag)	–	–0.3 to 10	V
Maximum Current into all pins except V_{CC} (6), HV (8) and Demag (1) when 10 V ESD diodes are activated	–	5.0	mA
Maximum Current in Pin 1	Idem	+3.0/–2.0	mA
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	57	°C/W
Thermal Resistance, Junction–to–Air, SOIC version	$R_{\theta JA}$	178	°C/W
Thermal Resistance, Junction–to–Air, DIP8 version	$R_{\theta JA}$	100	°C/W
Maximum Junction Temperature	TJ_{MAX}	150	°C
Temperature Shutdown	–	155	°C
Hysteresis in Shutdown	–	30	°C
Storage Temperature Range	–	–60 to +150	°C
ESD Capability, HBM Model (All pins except HV)	–	2.0	kV
ESD Capability, Machine Model	–	200	V
Maximum Voltage on Pin 8 (HV), Pin 6 (V_{CC}) decoupled to ground with 10 μF	V_{HVMAX}	500	V
Minimum Voltage on Pin 8 (HV), Pin 6 (V_{CC}) decoupled to ground with 10 μF	V_{HVMIN}	40	V

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS (For typical values $T_J = 25°C$, for min/max values $T_J = 0°C$ to $+125°C$, Max $T_J = 150°C$, $V_{CC} = 11$ V unless otherwise noted)

Rating	Pin	Symbol	Min	Typ	Max	Unit
DYNAMIC SELF–SUPPLY						
V_{CC} Increasing Level at which the Current Source Turns–off	6	VCC_{OFF}	10.8	12	12.9	V
V_{CC} Decreasing Level at which the Current Source Turns–on	6	VCC_{ON}	9.1	10	10.6	V
V_{CC} Decreasing Level at which the Latchoff Phase Ends	6	VCC_{latch}	–	5.3	–	V
V_{CC} Level at which Output Pulses are Disabled	6	UVLO	–	VCC_{ON} –200mV	–	V
Internal IC Consumption, No Output Load on Pin 5, $F_{SW} = 60$ kHz	6	ICC1	–	1.0	1.3 (Note 1)	mA
Internal IC Consumption, 1.0 nF Output Load on Pin 5, $F_{SW} = 60$ kHz	6	ICC2	–	1.6	2.0 (Note 1)	mA
Internal IC Consumption in Latchoff Phase	6	ICC3	–	330	–	μA
INTERNAL STARTUP CURRENT SOURCE ($T_J > 0°C$)						
High–voltage Current Source, $V_{CC} = 10$ V	8	IC1	4.3	7.0	9.6	mA
High–voltage Current Source, $V_{CC} = 0$	8	IC2	–	8.0	–	mA
DRIVE OUTPUT						
Output Voltage Rise–time @ CL = 1.0 nF, 10–90% of Output Signal	5	T_r	–	40	–	ns
Output Voltage Fall–time @ CL = 1.0 nF, 10–90% of Output Signal	5	T_f	–	20	–	ns
Source Resistance	5	R_{OH}	12	20	36	Ω
Sink Resistance	5	R_{OL}	5.0	10	19	Ω
CURRENT COMPARATOR (Pin 5 Unloaded)						
Input Bias Current @ 1.0 V Input Level on Pin 3	3	I_{IB}	–	0.02	–	μA
Maximum Internal Current Setpoint	3	I_{Limit}	0.92	1.0	1.12	V
Propagation Delay from Current Detection to Gate OFF State	3	T_{DEL}	–	100	160	ns
Leading Edge Blanking Duration	3	T_{LEB}	–	380	–	ns
Internal Current Offset Injected on the CS Pin during OFF Time	3	Iskip	–	200	–	μA
OVERVOLTAGE SECTION ($V_{CC} = 11$ V)						
Sampling Delay after ON Time	1	T_{sample}	–	4.5	–	μs
OVP Internal Reference Level	1	V_{ref}	6.4	7.2	8.0	V
FEEDBACK SECTION ($V_{CC} = 11$ V, Pin 5 Loaded by 1.0 kΩ)						
Internal Pull–up Resistor	2	Rup	–	20	–	kΩ
Pin 3 to Current Setpoint Division Ratio	–	Iratio	–	3.3	–	–
Internal Soft–start	–	Tss	–	1.0	–	ms
DEMAGNETIZATION DETECTION BLOCK						
Input Threshold Voltage (Vpin 1 Decreasing)	1	V_{th}	35	50	90	mV
Hysteresis (Vpin 1 Decreasing)	1	V_H	–	20	–	mV
Input Clamp Voltage High State (Ipin 1 = 3.0 mA) Low State (Ipin 1 = –2.0 mA)	1 1	VC_H VC_L	8.0 –0.9	10 –0.7	12 –0.5	V V
Demag Propagation Delay	1	T_{dem}	–	210	–	ns
Internal Input Capacitance at Vpin 1 = 1.0 V	1	C_{par}	–	10	–	pF
Minimum T_{OFF} (Internal Blanking Delay after T_{ON})	1	T_{blank}	–	8.0	–	μs
Timeout After Last Demag Transition	1	T_{out}	–	5.0	–	μs
Pin 1 Internal Impedance	1	R_{int}	–	28	–	kΩ

1. Max value at $T_J = 0°C$.

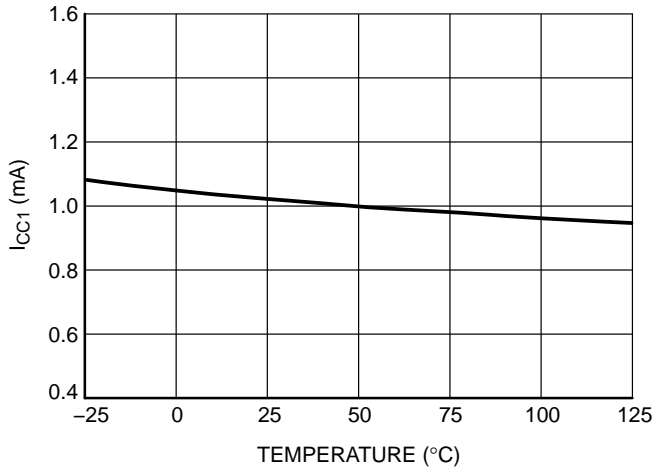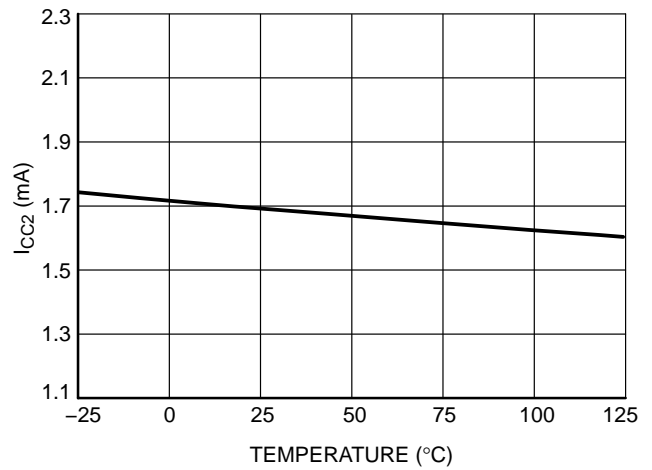**Figure 3. Internal IC Consumption (No Output Load) versus Temperature**

Figure 4. Internal IC Consumption (1.0 nF Output Load) versus Temperature
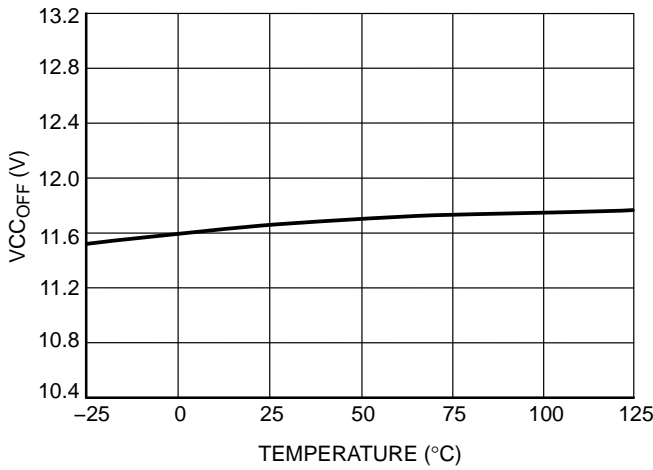
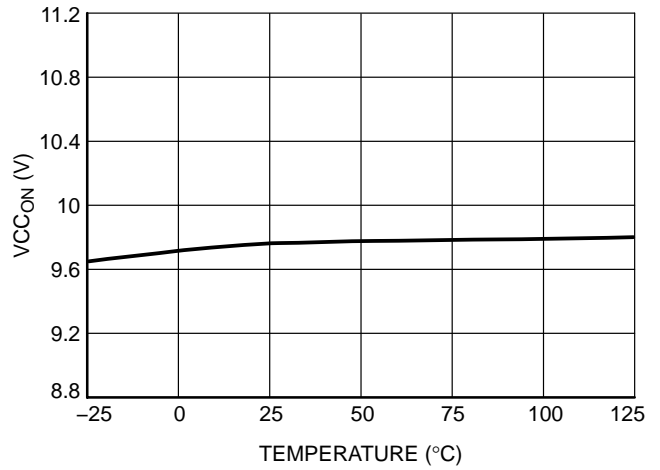**Figure 5. VCC Increasing Level at which the Current Source Turns−Off versus Temperature**

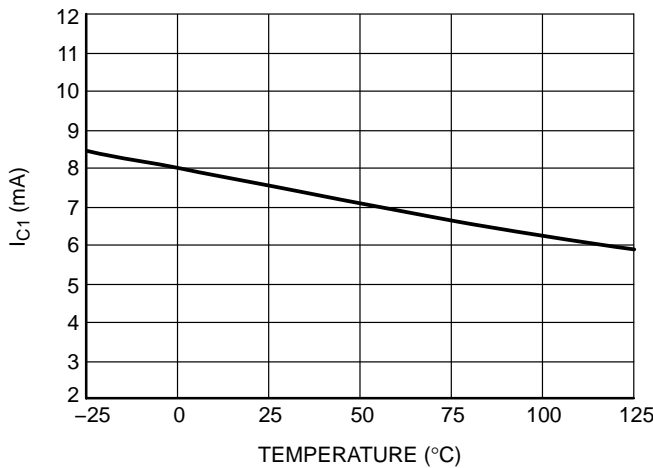**Figure 6. VCC Decreasing Level at which the Current Source Turns−On versus Temperature**

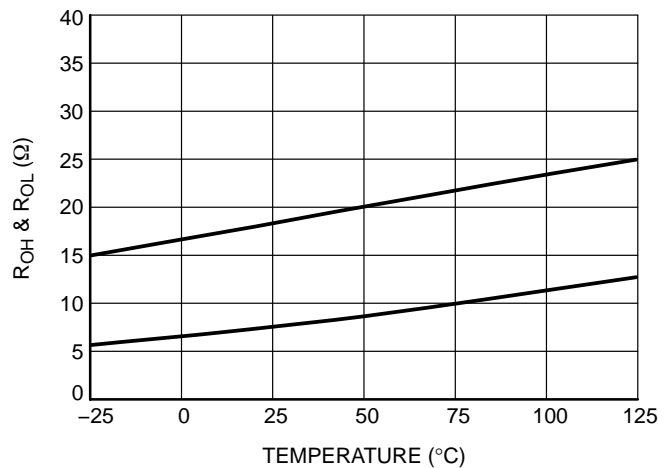**Figure 7. Internal Startup Current Source at V_{CC} = 10 V versus Temperature**
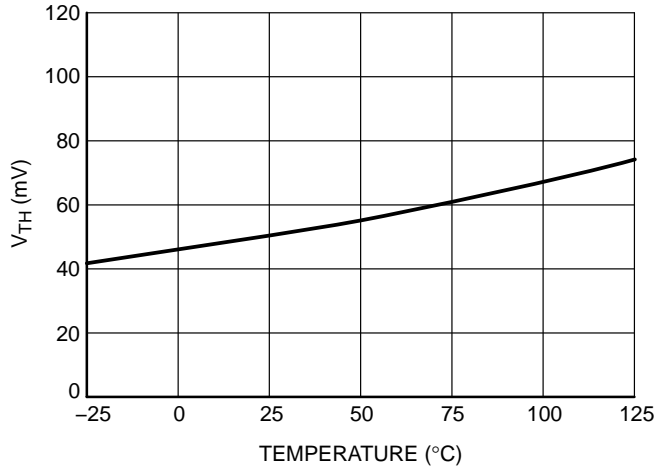
Figure 8. Source and Sink Resistance versus Temperature

Figure 9. Input Voltage (Vpin1 Decreasing) versus Temperature
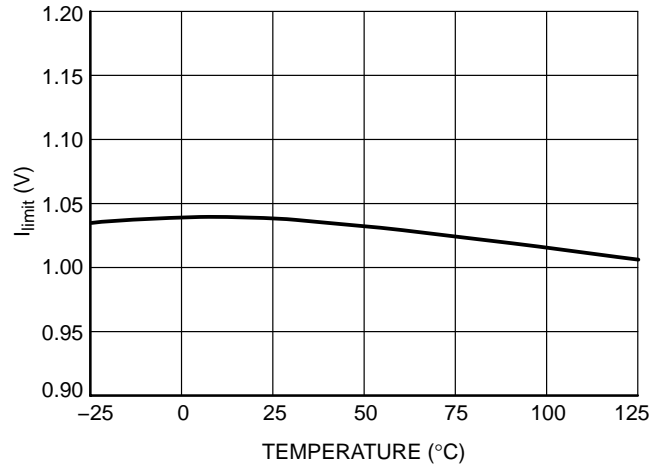
Figure 10. Maximum Internal Current Setpoint versus Temperature
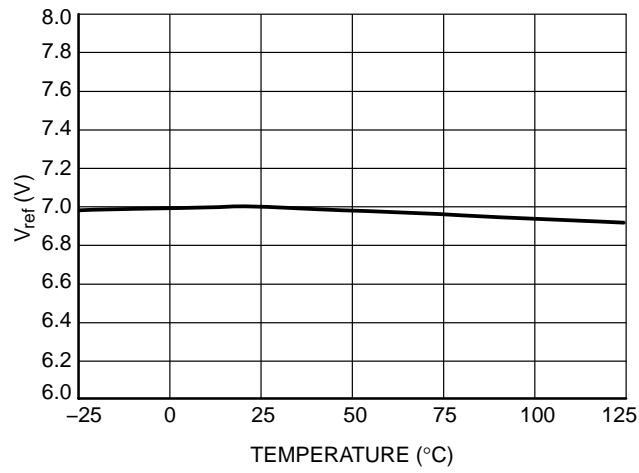
Figure 11. OVP internal Reference Level versus Temperature

NCP1207A

APPLICATION INFORMATION

Introduction

The NCP1207A implements a standard current mode architecture where the switch−off time is dictated by the peak current setpoint whereas the core reset detection triggers the turn−on event. This component represents the ideal candidate where low part−count is the key parameter, particularly in low−cost AC/DC adapters, consumer electronics, auxiliary supplies, etc. Thanks to its high−performance High−Voltage technology, the NCP1207A incorporates all the necessary components / features needed to build a rugged and reliable Switch−Mode Power Supply (SMPS):

- *Transformer core reset detection:* borderline / critical operation is ensured whatever the operating conditions are. As a result, there are virtually no primary switch turn−on losses and no secondary diode recovery losses. The converter also stays a first−order system and accordingly eases the feedback loop design.

- *Quasi−resonant operation:* by delaying the turn−on event, it is possible to re−start the MOSFET in the minimum of the drain−source wave, ensuring reduced EMI / video noise perturbations. In nominal power conditions, the NCP1207A operates in Borderline Conduction Mode (BCM) also called Critical Conduction Mode.

- *Dynamic Self−Supply (DSS):* due to its Very High Voltage Integrated Circuit (VHVIC) technology, ON Semiconductor's NCP1207A allows for a direct pin connection to the high−voltage DC rail. A dynamic current source charges up a capacitor and thus provides a fully independent V_{CC} level to the NCP1207A. As a result, there is no need for an auxiliary winding whose management is always a problem in variable output voltage designs (e.g. battery chargers).

- *Overvoltage Protection (OVP):* by sampling the plateau voltage on the demagnetization winding, the NCP1207A goes into latched fault condition whenever an over−voltage condition is detected. The controller stays fully latched in this position until the V_{CC} is cycled down 4.0 V, e.g. when the user un−plugs the power supply from the mains outlet and re−plugs it.

- *External latch trip point:* by externally forcing a level on the OVP greater than the internal setpoint, it is possible to latchoff the IC, e.g. with a signal coming from a temperature sensor.

- *Adjustable skip cycle level:* by offering the ability to tailor the level at which the skip cycle takes place, the designer can make sure that the skip operation only occurs at low peak current. This point guarantees a noise−free operation with cheap transformer. This option also offers the ability to fix the maximum switching frequency when entering light load conditions.

- *Overcurrent Protection (OCP):* by continuously monitoring the FB line activity, NCP1207A enters burst mode as soon as the power supply undergoes an overload. The device enters a safe low power operation which prevents from any lethal thermal runaway. As soon as the default disappears, the power supply resumes operation. Unlike other controllers, overload detection is performed independently of any auxiliary winding level. In presence of a bad coupling between both power and auxiliary windings, the short circuit detection can be severely affected. The DSS naturally shields you against these troubles.

Dynamic Self−Supply

The DSS principle is based on the charge/discharge of the V_{CC} bulk capacitor from a low level up to a higher level. We can easily describe the current source operation with some simple logical equations:

POWER−ON: IF $V_{CC} <$ VCC$_{OFF}$ THEN Current Source is ON, no output pulses

IF V_{CC} decreasing $>$ VCC$_{ON}$ THEN Current Source is OFF, output is pulsing

IF V_{CC} increasing $<$ VCC$_{OFF}$ THEN Current Source is ON, output is pulsing

Typical values are: VCC$_{OFF} = 12$ V, VCC$_{ON} = 10$ V

To better understand the operational principle, Figure 12's sketch offers the necessary light.

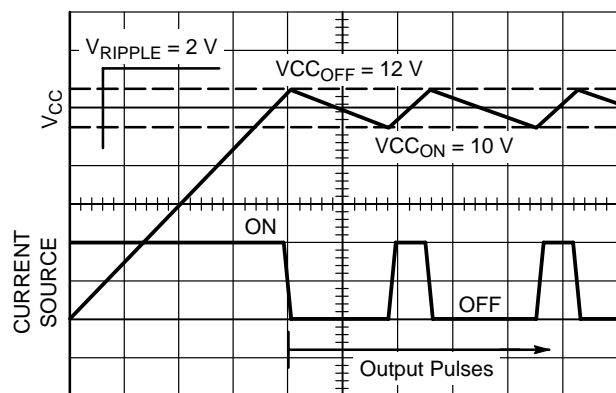**Figure 12. The Charge/Discharge Cycle Over a 10 μF V_{CC} Capacitor**

The DSS behavior actually depends on the internal IC consumption and the MOSFET's gate charge Qg. If we select a MOSFET like the MTP2N60E, Qg equals 22 nC (max). With a maximum switching frequency selected at 75 kHz, the average power necessary to drive the MOSFET (excluding the driver efficiency and neglecting various voltage drops) is:

$Fsw \cdot Qg \cdot V_{CC}$ with:

Fsw = maximum switching frequency

Qg = MOSFET's gate charge

V_{CC} = V_{GS} level applied to the gate

To obtain the output current, simply divide this result by V_{CC}: $I_{driver} = F_{SW} \cdot Qg = 1.6$ mA. The total standby power consumption at no−load will therefore heavily rely on the internal IC consumption plus the above driving current (altered by the driver's efficiency). Suppose that the IC is supplied from a 350 VDC line. The current flowing through pin 8 is a direct image of the NCP1207A consumption (neglecting the switching losses of the HV current source). If I_{CC2} equals 2.3 mA @ T_J = 60°C, then the power dissipated (lost) by the IC is simply: 350 V x 2.3 mA = 805 mW. For design and reliability reasons, it would be interested to reduce this source of wasted power that increase the die temperature. This can be achieved by using different methods:

1. Use a MOSFET with lower gate charge Qg.
2. Connect pin 8 through a diode (1N4007 typically) to one of the mains input. The average value on pin 8 becomes $\frac{VmainsPEAK \cdot 2}{\pi}$. Our power contribution example drops to: 223 V x 2.3 mA = 512 mW. If a resistor is installed between the mains and the diode, you further force the dissipation to migrate from the package to the resistor. The resistor value should account for low−line startups.
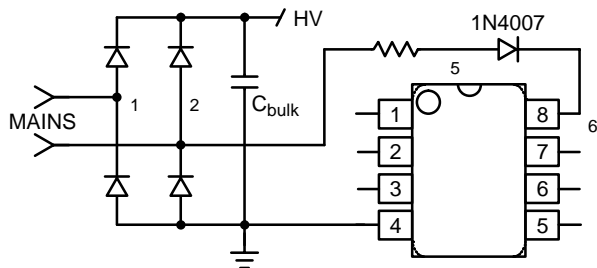
When using Figure 13 option, it is important to check the absence of any negative ringing that could occur on pin 8. The resistor in series should help to damp any parasitic LC network that would ring when suddenly applying the power to the IC. Also, since the power disappears during 10 ms (half−wave rectification), CV_{CC} should be calculated to supply the IC during these holes in the supply

3. Permanently force the V_{CC} level above V_{CCH} with an auxiliary winding. It will automatically disconnect the internal startup source and the IC will be fully self−supplied from this winding. Again, the total power drawn from the mains will significantly decrease. Make sure the auxiliary voltage never exceeds the 16 V limit.

Skipping Cycle Mode

The NCP1207A automatically skips switching cycles when the output power demand drops below a given level. This is accomplished by monitoring the FB pin. In normal operation, Pin 2 imposes a peak current accordingly to the load value. If the load demand decreases, the internal loop asks for less peak current. When this setpoint reaches a determined level, the IC prevents the current from decreasing further down and starts to blank the output pulses: the IC enters the so−called skip cycle mode, also named controlled burst operation. The power transfer now depends upon the width of the pulse bunches (Figure 14) and follows the following formula:

$\frac{1}{2} \cdot Lp \cdot Ip^2 \cdot Fsw \cdot D_{burst}$ with:

Lp = primary inductance

Fsw = switching frequency within the burst

Ip = peak current at which skip cycle occurs

D_{burst} = burst width / burst recurrence

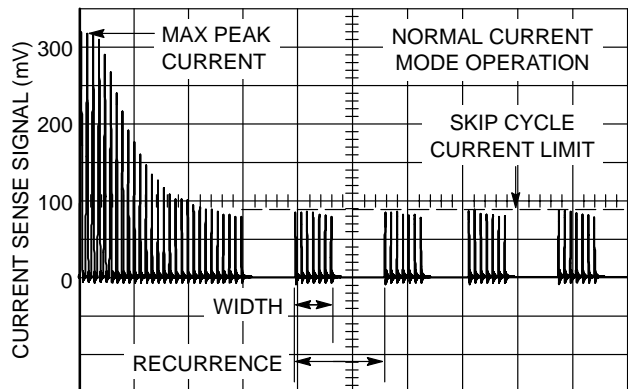**Figure 13. A simple diode naturally reduces the average voltage on Pin 8**

Figure 14. The skip cycle takes place at low peak currents which guaranties noise free operation
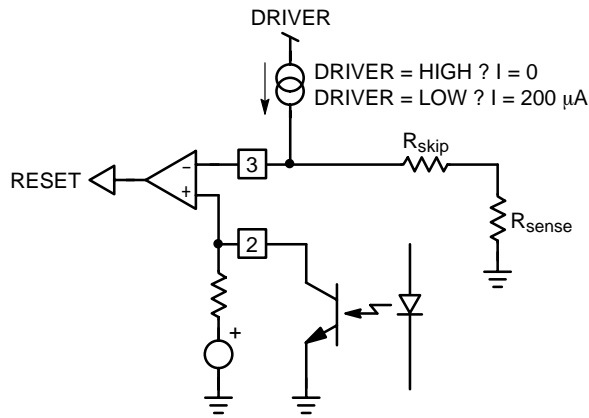
Figure 15. A patented method allows for skip level selection via a series resistor inserted in series with the current

The skip level selection is done through a simple resistor inserted between the current sense input and the sense element. Every time the NCP1207A output driver goes low, a 200 μA source forces a current to flow through the sense pin (Figure 15): when the driver is high, the current source is off and the current sense information is normally processed. As soon as the driver goes low, the current source delivers 200 μA and develops a ground referenced voltage across R_{skip}. If this voltage is below the feedback voltage, the current sense comparator stays in the high state and the internal latch can be triggered by the next clock cycle. Now, if because of a low load mode the feedback voltage is below R_{skip} level, then the

current sense comparator permanently resets the latch and the next clock cycle (given by the demagnetization detection) is ignored: we are skipping cycles as shown by Figure 16. As soon as the feedback voltage goes up again, there can be two situations: the recurrent period is small and a new demagnetization detection (next wave) signal triggers the NCP1207A. To the opposite, in low output power conditions, no more ringing waves are present on the drain and the toggling of the current sense comparator together with the internal 5 μs timeout initiates a new cycle start. In normal operating conditions, e.g. when the drain oscillations are generous, the demagnetization comparator can detect the 50 mV crossing and gives the "green light", alone, to re–active the power switch. However, when skip cycle takes place (e.g. at low output power demands), the re–start event slides along the drain ringing waveforms (actually the valley locations) which decays more or less quickly, depending on the $L_{primary}$–$C_{parasitic}$ network damping factor. The situation can thus quickly occur where the ringing becomes too weak to be detected by the demagnetization comparator: it then permanently stays locked in a given position and can no longer deliver the "green light" to the controller. To help in this situation, the NCP1207A implements a 5 μs timeout generator: each time the 50 mV crossing occurs, the timeout is reset. So, as long as the ringing becomes too low, the timeout generator starts to count and after 5 μs, it delivers its "green light". If the skip signal is already present then the controller re–starts; otherwise the logic waits for it to set the drive output high. Figure 16 depicts these two different situations:
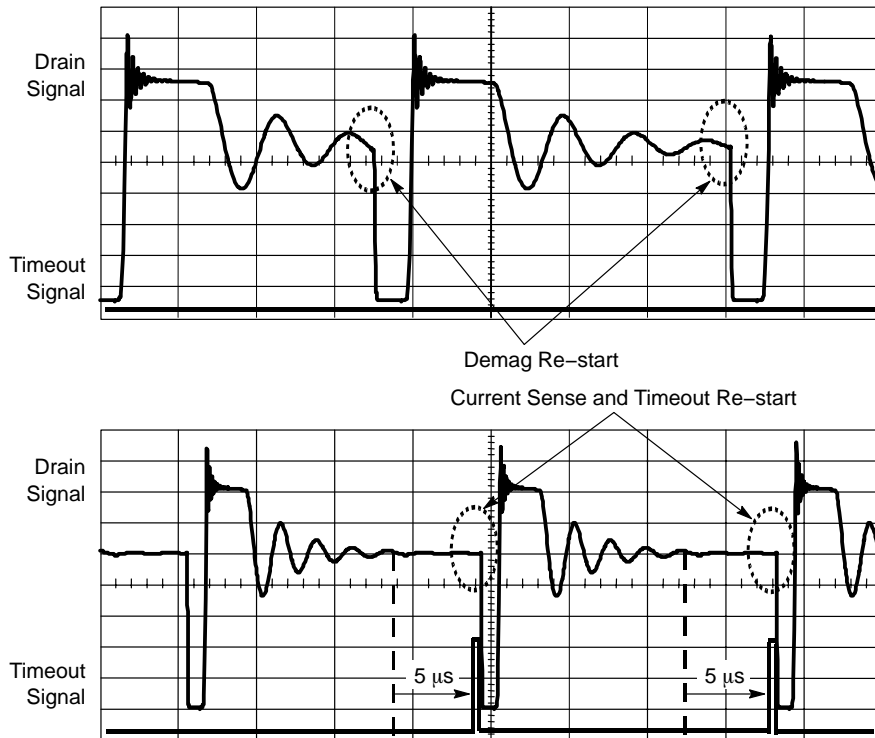

Figure 16. When the primary natural ringing becomes too low, the internal timeout together with the sense comparator initiates a new cycle when FB passes the skip level.

Demagnetization Detection

The core reset detection is done by monitoring the voltage activity on the auxiliary winding. This voltage features a FLYBACK polarity. The typical detection level is fixed at 50 mV as exemplified by Figure 17.
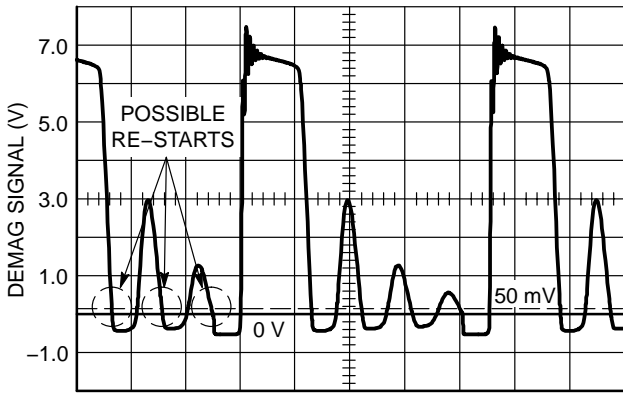

Figure 17. Core reset detection is done through a dedicated auxiliary winding monitoring
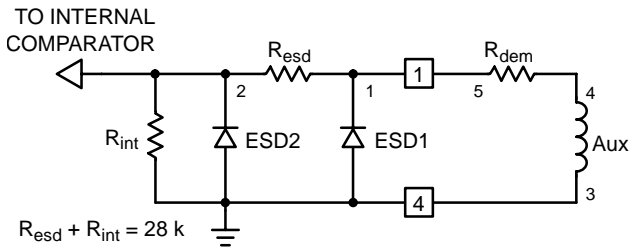

Figure 18. Internal Pad Implementation

An internal timer prevents any re−start within 8.0 μs further to the driver going−low transition. This prevents the switching frequency to exceed $(1 / (T_{ON} + 8.0 \text{ μs}))$ but also avoid false leakage inductance tripping at turn−off. In some cases, the leakage inductance kick is so energetic, that a slight filtering is necessary.

The 1207 demagnetization detection pad features a specific component arrangement as detailed by Figure 18. In this picture, the zener diodes network protect the IC against any potential ESD discharge that could appear on the pins. The first ESD diode connected to the pad, exhibits a parasitic capacitance. When this parasitic capacitance (10 pF typically) is combined with R_{dem}, a re−start delay is created and the possibility to switch right in the drain−source wave exists. This guarantees QR operation with all the associated benefits (low EMI, no turn−on losses etc.). R_{dem} should be calculated to limit the maximum current flowing through pin 1 to less than +3 mA/−2 mA. If during turn−on, the auxiliary winding delivers 30 V (at the highest line level), then the minimum R_{dem} value is defined by: $(30 \text{ V} + 0.7 \text{ V})$ / 2 mA = 14.6 kΩ. This value will be further increased to introduce a re−start delay and also a slight filtering in case of high leakage energy.

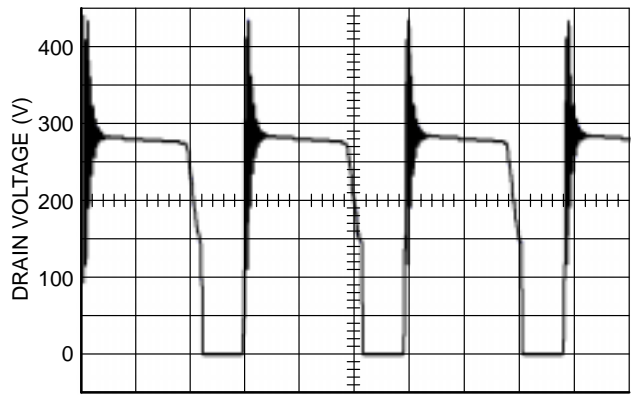Figure 19 portrays a typical V_{DS} shot at nominal output power.

Figure 19. The NCP1207A Operates in Borderline / Critical Operation

Overvoltage Protection

The overvoltage protection works by sampling the plateau voltage 4.5 μs after the turn−off sequence. This delay guarantees a clean plateau, providing that the leakage inductance ringing has been fully damped. If this would not be the case, the designer should install a small RC damper across the transformer primary inductance connections. Figure 20 shows where the sampling occurs on the auxiliary winding.
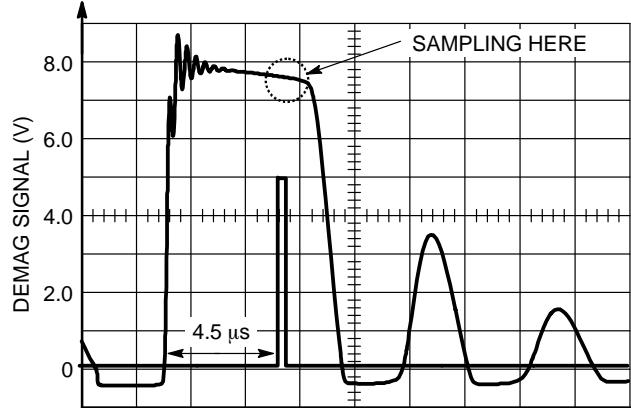

Figure 20. A voltage sample is taken 4.5 μs after the turn−off sequence

When an OVP condition has been detected, the NCP1207A enters a latchoff phase and stops all switching operations. The controller stays fully latched in this position and the DSS is still active, keeping the V_{CC} between 5.3 V/12 V as in normal operations. This state lasts until the V_{CC} is cycled down 4 V, e.g. when the user unplugs the power supply from the mains outlet.

By default, the OVP comparator is biased to a 5 V reference level and pin1 is routed via a divide by 1.44 network. As a result, when Vpin 1 reaches 7.2 V, the OVP comparator is triggered. The threshold can thus be adjusted by either modifying the power winding to auxiliary winding turn ratios to match this 7.2 V level, or insert a resistor from Pin 1 to ground to cope with your design requirement.

Latching Off the NCP1207A

In certain cases, it can be very convenient to externally shut down permanently the NCP1207A via a dedicated signal, e.g. coming from a temperature sensor. The reset occurs when the user unplugs the power supply from the mains outlet. To trigger the latchoff, a CTN (Figure 21) or a simple NPN transistor (Figure 22) can do the work.
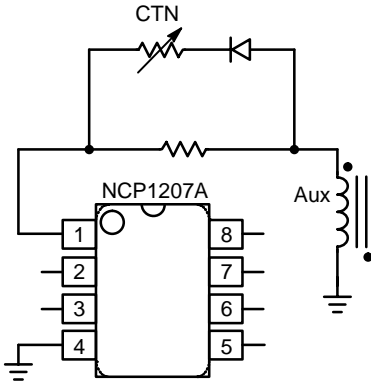

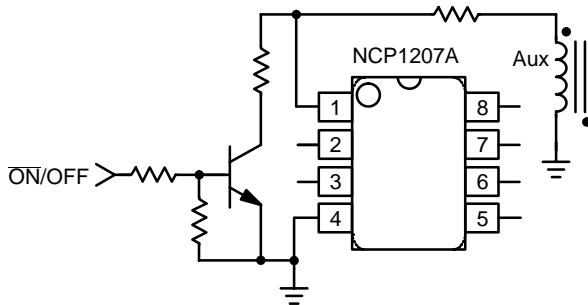**Figure 21. A simple CTN triggers the latchoff as soon as the temperature exceeds a given setpoint**

Figure 22. A simple transistor arrangement allows to trigger the latchoff by an external signal

Shutting Off the NCP1207A

Shutdown can easily be implemented through a simple NPN bipolar transistor as depicted by Figure 23. When OFF, Q1 is transparent to the operation. When forward biased, the transistor pulls the FB pin to ground ($V_{CE(sat)} \approx 200$ mV) and permanently disables the IC. A small time constant on the transistor base will avoid false triggering (Figure 23).
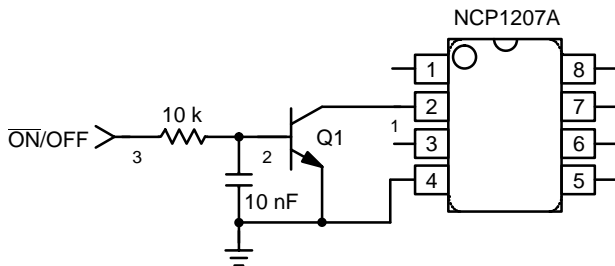
Figure 23. A simple bipolar transistor totally disables the IC

Power Dissipation

The NCP1207A is directly supplied from the DC rail through the internal DSS circuitry. The DSS being an auto–adaptive circuit (e.g. the ON/OFF duty–cycle adjusts itself depending on the current demand), the current flowing through the DSS is therefore the direct image of the NCP1207A current consumption. The total power dissipation can be evaluated using: $(V_{HVDC} - 11$ V$) \cdot I_{CC2}$. If we operate the device on a 250 Vac rail, the maximum rectified voltage can go up to 350 Vdc. As a result, the worse case dissipation occurs at the maximum switching frequency and the highest line. The dissipation is actually given by the internal consumption of the NCP1207A when driving the selected MOSFET. The best method to evaluate this total consumption is probably to run the final circuit from a 50 Vdc source applied to pin 8 and measure the average current flowing into this pin. Suppose that we find 2.0 mA, meaning that the DSS duty–cycle will be $2.0/7.0 = 28.6\%$. From the 350 Vdc rail, the part will dissipate: 350 V $\cdot$ 2.0 mA = 700 mW (however this 2.0 mA number will drop at higher operating junction temperatures). A DIP8 package offers a junction–to–ambient thermal resistance $R_{\theta JA}$ of 100°C/W. The maximum power dissipation can thus be computed knowing the maximum operating ambient temperature (e.g. 70°C) together with the maximum allowable junction temperature (125°C):

$$P_{max} = \frac{T_{jmax} - T_{Amax}}{R_{\theta JA}} < 550 \text{ mW.}$$ As we can see, we do not reach the worse consumption budget imposed by the operating conditions. Several solutions exist to cure this trouble:

- The first one consists in adding some copper area around the NCP1207A DIP8 footprint. By adding a min pad area of 80 mm² of 35 μm copper (1 oz.), $R_{\theta JA}$ drops to about 75°C/W. Maximum power then grows up to 730 mW.

- *A resistor R_{drop} needs to be inserted with pin 8 to* a) avoid negative spikes at turn–off (see below)
b) split the power budget between this resistor and the package. The resistor is calculated by leaving at least 50 V on pin 8 at minimum input voltage (suppose 100 Vdc in our case): $R_{drop} \leq \dfrac{V_{bulkmin} - 50 \text{ V}}{7.0 \text{ mA}} < 7.1$ kΩ. The power dissipated by the resistor is thus:

$$P_{drop} = V_{dropRMS}^2 / R_{drop}$$
$$= \frac{\left(I_{DSS} \cdot R_{drop} \cdot \sqrt{DSS_{duty - cycle}}\right)^2}{R_{drop}}$$
$$= \frac{\left(7.0 \text{ mA} \cdot 7.1 \text{ k}\Omega \cdot \sqrt{0.286}\right)^2}{7.1 \text{ k}\Omega} = 99.5 \text{ mW}$$

Please refer to the application note AND8069 available from www.onsemi.com/pub/ncp1200.

• If the power consumption budget is really too high for the DSS alone, connect a diode between the auxiliary winding and the V_{CC} pin which will disable the DSS operation (V_{CC} > 10 V).

The SOIC package offers a 178°C/W thermal resistor. Again, adding some copper area around the PCB footprint will help decrease this number: 12 mm × 12 mm to drop $R_{\theta JA}$ down to 100°C/W with 35 μm copper thickness (1 oz) or 6.5 mm × 6.5 mm with 70 μm copper thickness (2 oz). As one can see, we do not recommend using the SO–8 package and the DSS if the part operates at high switching frequencies. In that case, an auxiliary winding is the best solution.

Overload Operation

In applications where the output current is purposely not controlled (e.g. wall adapters delivering raw DC level), it is interesting to implement a true short–circuit protection. A short–circuit actually forces the output voltage to be at a low level, preventing a bias current to circulate in the Optocoupler LED. As a result, the FB pin level is pulled up to 4.2 V, as internally imposed by the IC. The peak current setpoint goes to the maximum and the supply delivers a rather high power with all the associated effects. Please note that this can also happen in case of feedback loss, e.g. a broken Optocoupler. To account for this situation,

NCP1207A hosts a dedicated overload detection circuitry. Once activated, this circuitry imposes to deliver pulses in a burst manner with a low duty–cycle. The system recovers when the fault condition disappears.

During the startup phase, the peak current is pushed to the maximum until the output voltage reaches its target and the feedback loop takes over. This period of time depends on normal output load conditions and the maximum peak current allowed by the system. The time–out used by this IC works with the V_{CC} decoupling capacitor: as soon as the V_{CC} decreases from the VCC_{OFF} level (typically 12 V) the device internally watches for an overload current situation. If this condition is still present when the VCC_{ON} level is reached, the controller stops the driving pulses, prevents the self–supply current source to restart and puts all the circuitry in standby, consuming as little as 330 μA typical (I_{CC3} parameter). As a result, the V_{CC} level slowly discharges toward 0. When this level crosses 5.3 V typical, the controller enters a new startup phase by turning the current source on: V_{CC} rises toward 12 V and again delivers output pulses at the VCC_{OFF} crossing point. If the fault condition has been removed before VCC_{ON} approaches, then the IC continues its normal operation. Otherwise, a new fault cycle takes place. Figure 24 shows the evolution of the signals in presence of a fault.
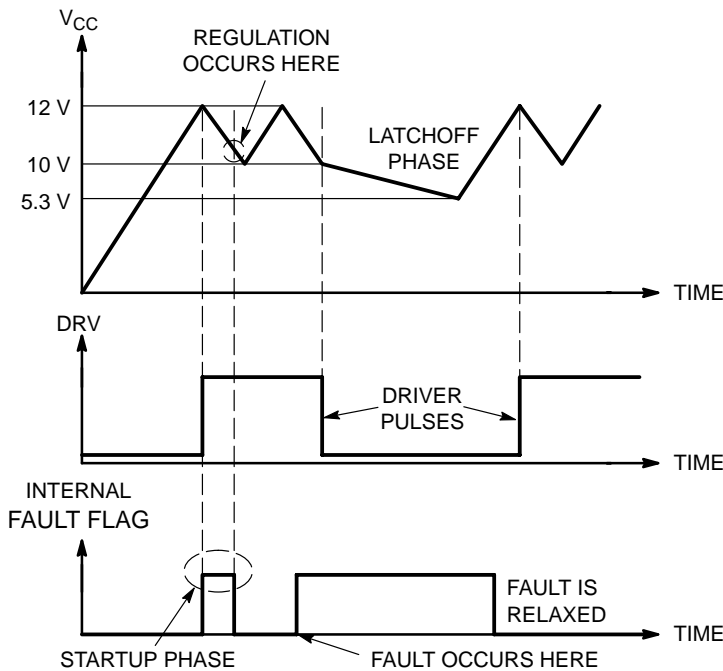
If the fault is relaxed during the Vcc natural fall down sequence, the IC automatically resumes.
If the fault still persists when Vcc reached VCC_{ON}, then the controller cuts everything off until recovery.

Figure 24.

Soft–Start

The NCP1207A features an internal 1 ms soft–start to soften the constraints occurring in the power supply during startup. It is activated during the power on sequence. As soon as V_{CC} reaches VCC_{OFF}, the peak current is gradually increased from nearly zero up to the maximum clamping level (e.g. 1.0 V). The soft–start is also activated during the overcurrent burst (OCP) sequence. Every restart attempt is followed by a soft–start activation. Generally speaking, the soft–start will be activated when V_{CC} ramps up either from zero (fresh power–on sequence) or 5.3 V, the latchoff voltage occurring during OCP.

NCP1207A

Calculating the Vcc Capacitor

As the above section describes, the fall down sequence depends upon the V_{CC} level: how long does it take for the V_{CC} line to go from 12 V to 10 V? The required time depends on the startup sequence of your system, i.e. when you first apply the power to the IC. The corresponding transient fault duration due to the output capacitor charging must be less than the time needed to discharge from 12 V to 10 V, otherwise the supply will not properly start. The test consists in either simulating or measuring in the lab how much time the system takes to reach the regulation at full load. Let's suppose that this time corresponds to 6.0 ms. Therefore a V_{CC} fall time of 10 ms could be well appropriated in order to not trigger the overload detection circuitry. If the corresponding IC consumption, including the MOSFET drive, establishes at 1.8 mA (e.g. with an 11 nC MOSFET), we can calculate the required capacitor using the following formula: $\Delta t = \dfrac{\Delta V \cdot C}{i}$, with $\Delta V = 2.0$ V. Then for a wanted Δt of 10 ms, C equals 9.0 μF or 22 μF for a standard value. When an overload condition occurs, the IC blocks its internal circuitry and its consumption drops to 330 μA typical. This happens at $V_{CC} = 10$ V and it remains stuck until V_{CC} reaches 5.3 V: we are in latchoff phase. Again, using the calculated 22 μF and 330 μA current consumption, this latchoff phase lasts: 313 ms.

HV Pin Recommended Protection

When the user unplugs a power supply built with a QR controller such as the NCP1207A, two phenomena can appear:

1. A negative ringing can take place on pin8 due to a resonance between the primary inductance and the bulk capacitor. As any CMOS device, the NCP1207A is sensitive to negative voltages that could appear on it's pins and could create an internal latch–up condition.
2. When the bulk capacitor discharges, the internal latch is reset by the voltage developed over the sense resistor and the *ON* time expands as less voltage is available. When the high–voltage rail becomes too low, the gate drives permanently stays high since no reset occurs. This situation is not desirable in many applications.

For the above reasons, we strongly recommend to add a high–voltage diode like a 1N4007 between the bulk capacitor and the V_{CC} pin. When the bulk level collapses, it naturally shuts the controller down and eradicates the two above problems.
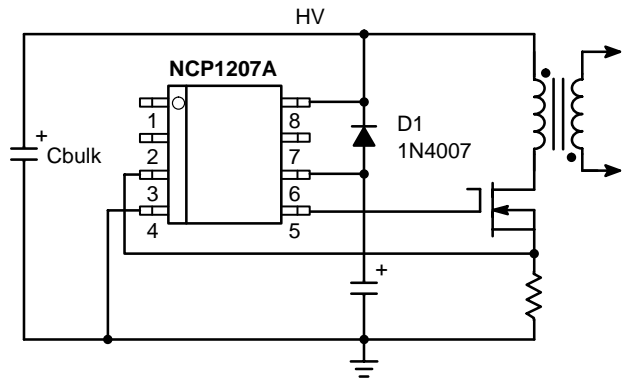

Figure 25.

Operation Shots

Below are some oscilloscope shots captured at $V_{in} = 120$ VDC with a transformer featuring a 800 μH primary inductance.
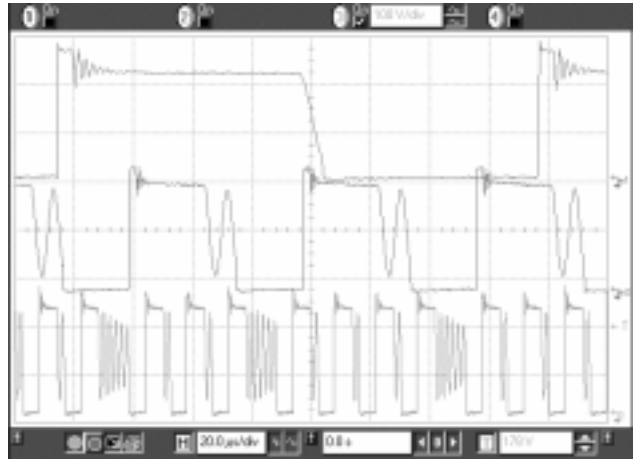

Figure 26.

This plot gathers waveforms captured at three different operating points:

1st upper plot: free run, valley switching operation, $P_{out} = 26$ W

2nd middle plot: min T_{off} clamps the switching frequency and selects the second valley

3rd lowest plot: the skip slices the second valley pattern and will further expand the burst as P_{out} goes low

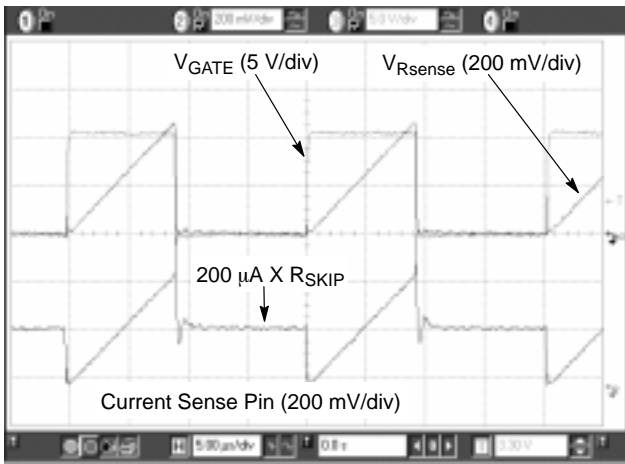**Figure 27.**

This picture explains how the 200 μA internal offset current creates the skip cycle level.
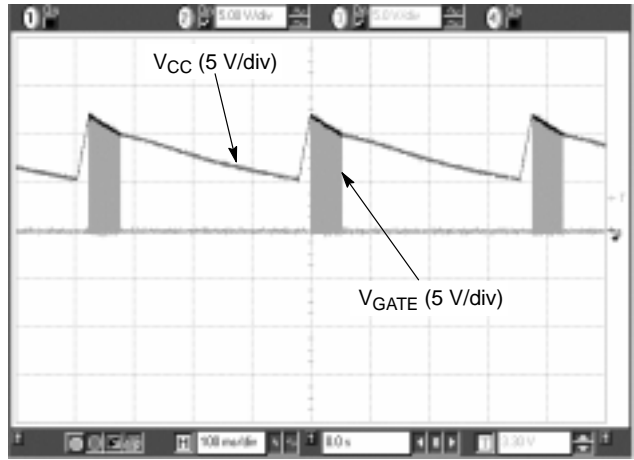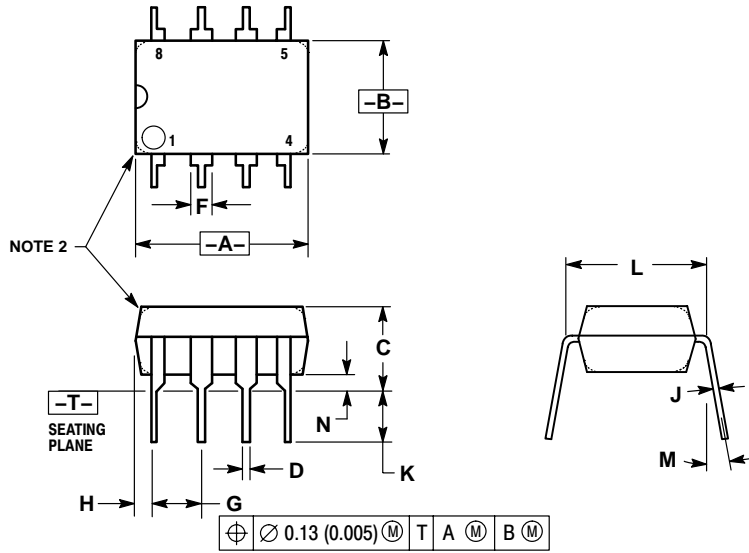

Figure 28.

The short−circuit protection forces the IC to enter burst in presence of a secondary overload.

NCP1207A

PACKAGE DIMENSIONS

PDIP−8
N SUFFIX
CASE 626−05
ISSUE L

NOTES:
1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

NOTE 2

−B−

−A−

F

−T−
SEATING PLANE

C

N

D

K

H

G

L

J

M

⊕ | ⌀ 0.13 (0.005) Ⓜ | T | A Ⓜ | B Ⓜ

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	---	10°	---	10°
N	0.76	1.01	0.030	0.040

NCP1207A

PACKAGE DIMENSIONS

(SO–8)
D1, D2 SUFFIX
CASE 751–07
ISSUE AB
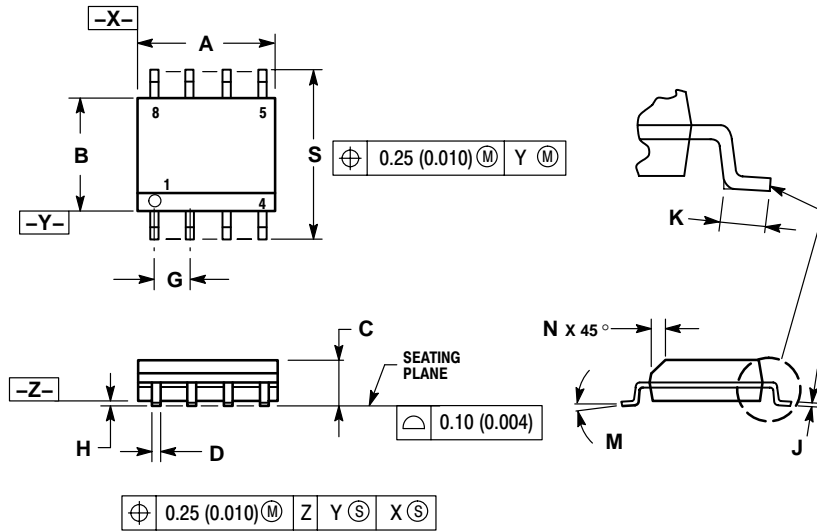
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDAARD IS 751–07

DIM	MILLIMETERS MIN	MILLIMETERS MAX	INCHES MIN	INCHES MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*

SCALE 6:1 $\left(\dfrac{mm}{inches}\right)$
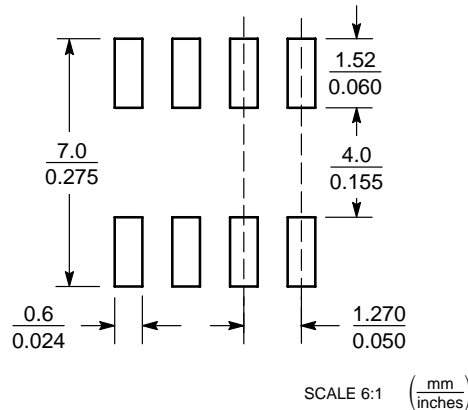
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

The product described herein (NCP1207A), may be covered by one or more of the following U.S. patents: 6,362,067, 6,385,060, 6,385,061, 6,429,709, 6,587,357, 6,633,193. There may be other patents pending.